



Is Now Part of



ON Semiconductor®

To learn more about ON Semiconductor, please visit our website at

www.onsemi.com

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.



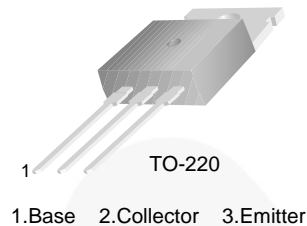
November 2014



TIP47 / TIP48 / TIP49 / TIP50 NPN Silicon Transistor

Features

- High-Voltage and Switching Applications
- High Sustaining Voltage: $V_{CEO(sus)} = 250\text{ V}, 300\text{ V}, 350\text{ V}, 400\text{ V}$
- 1 A Rated Collector Current



Ordering Information

Part Number	Top Mark	Package	Packing Method
TIP47	TIP47	TO-220 3L (Single Gauge)	Bulk
TIP47TU	TIP47	TO-220 3L (Single Gauge)	Rail
TIP48	TIP48	TO-220 3L (Single Gauge)	Bulk
TIP48TU	TIP48	TO-220 3L (Single Gauge)	Rail
TIP49	TIP49	TO-220 3L (Single Gauge)	Bulk
TIP50	TIP50	TO-220 3L (Single Gauge)	Bulk
TIP50TU	TIP50	TO-220 3L (Single Gauge)	Rail

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_C = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Value	Unit	
V_{CBO}	Collector-Base Voltage	TIP47	350	V
		TIP48	400	
		TIP49	450	
		TIP50	500	
V_{CEO}	Collector-Emitter Voltage	TIP47	250	V
		TIP48	300	
		TIP49	350	
		TIP50	400	
V_{EBO}	Emitter-Base Voltage	5	V	
I_C	Collector Current (DC)	1	A	
I_{CP}	Collector Current (Pulse)	2	A	
I_B	Base Current	0.6	A	
T_J	Junction Temperature	150	$^\circ\text{C}$	
T_{STG}	Storage Temperature Range	- 65 to 150	$^\circ\text{C}$	

TIP47 / TIP48 / TIP49 / TIP50 — NPN Silicon Transistor

Thermal Characteristics

Values are at $T_C = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Value	Unit
P_C	Collector Dissipation ($T_C = 25^\circ\text{C}$)	40	W
	Collector Dissipation ($T_A = 25^\circ\text{C}$)	2	

Electrical Characteristics

Values are at $T_C = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit	
$V_{CEO(sus)}$	Collector-Emitter Sustaining Voltage ⁽¹⁾	TIP47	$I_C = 30\text{ mA}, I_B = 0$	250			V
		TIP48		300			
		TIP49		350			
		TIP50		400			
I_{CEO}	Collector Cut-Off Current	TIP47	$V_{CE} = 150\text{ V}, I_B = 0$			1	mA
		TIP48	$V_{CE} = 200\text{ V}, I_B = 0$			1	
		TIP49	$V_{CE} = 250\text{ V}, I_B = 0$			1	
		TIP50	$V_{CE} = 300\text{ V}, I_B = 0$			1	
I_{CES}	Collector Cut-Off Current	TIP47	$V_{CE} = 350\text{ V}, V_{EB} = 0$			1	mA
		TIP48	$V_{CE} = 400\text{ V}, V_{EB} = 0$			1	
		TIP49	$V_{CE} = 450\text{ V}, V_{EB} = 0$			1	
		TIP50	$V_{CE} = 500\text{ V}, V_{EB} = 0$			1	
I_{EBO}	Emitter Cut-Off Current	$V_{BE} = 5\text{ V}, I_C = 0$			1	mA	
h_{FE}	DC Current Gain ⁽¹⁾	$V_{CE} = 10\text{ V}, I_C = 0.3\text{ A}$	30		150		
		$V_{CE} = 10\text{ V}, I_C = 1\text{ A}$	10				
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage ⁽¹⁾	$I_C = 1\text{ A}, I_B = 0.2\text{ A}$			1	V	
$V_{BE(on)}$	Base-Emitter On Voltage ⁽¹⁾	$V_{CE} = 10\text{ V}, I_C = 1\text{ A}$			1.5	V	
f_T	Current Gain Bandwidth Product	$V_{CE} = 10\text{ V}, I_C = 0.2\text{ A}, f = 1\text{ MHz}$	10			MHz	

Note:

1. Pulse test: $p_w \leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$.

Typical Performance Characteristics

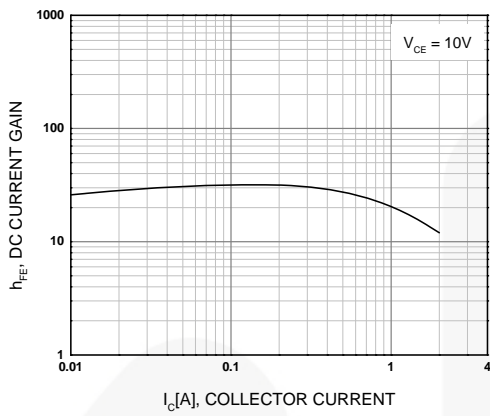


Figure 1. DC Current Gain

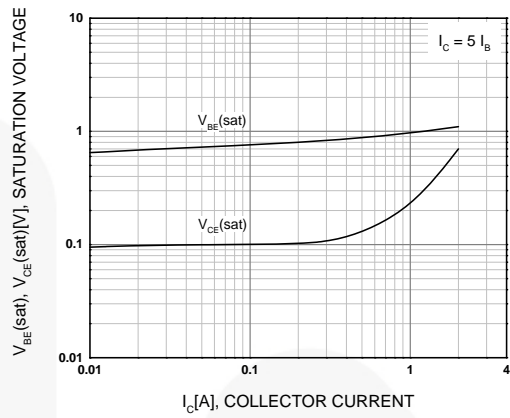


Figure 2. Collector-Emitter Saturation Voltage and Base-Emitter Saturation Voltage

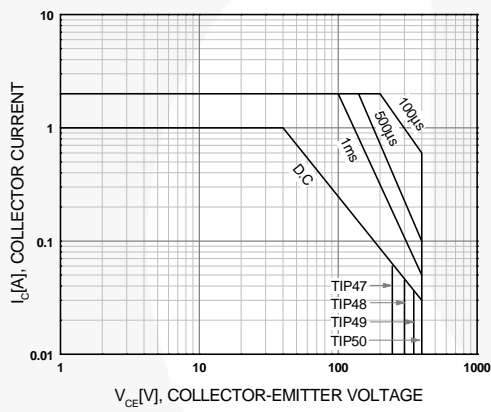


Figure 3. Safe Operating Area

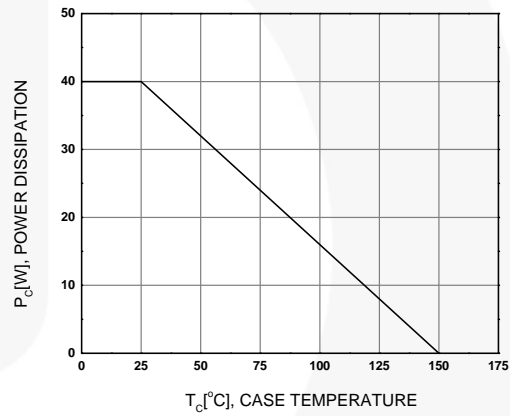


Figure 4. Power Derating

Physical Dimensions

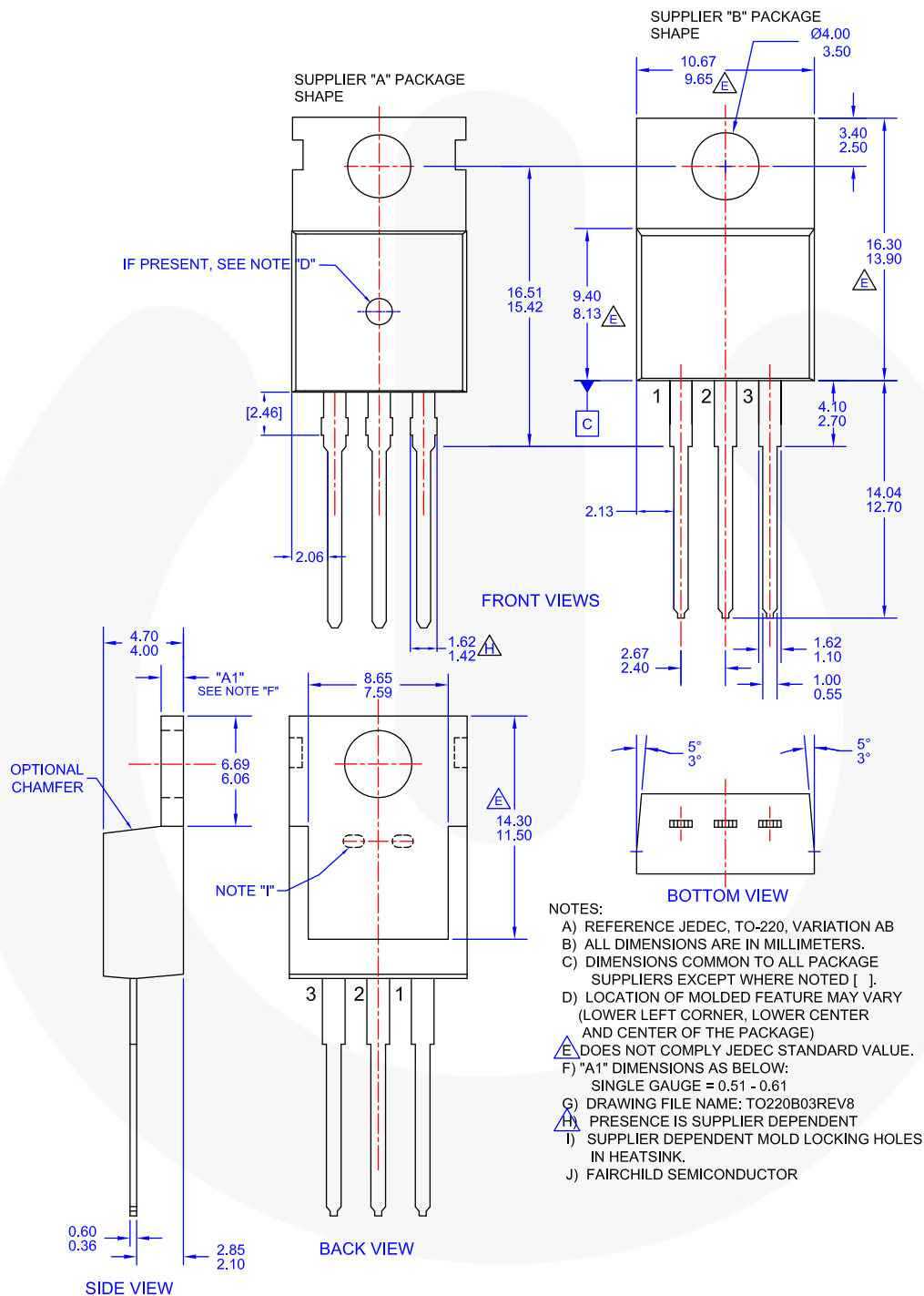


Figure 5. TO-220, MOLDED, 3LEAD, JEDEC VARIATION AB



TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

AccuPower™	F-PFS™	OPTOPLANAR®	 SYSTEM GENERAL®
Awinda®	FRFET®	 ®	TinyBoost®
AX-CAP®*	Global Power Resource™	PowerTrench®	TinyBuck®
BitSiC™	GreenBridge™	PowerXS™	TinyCalc™
Build it Now™	Green FPS™	Programmable Active Droop™	TinyLogic®
CorePLUS™	Green FPS™ e-Series™	QFET®	TINYOPTO™
CorePOWER™	Gmax™	QS™	TinyPower™
CROSSVOLT™	GTO™	Quiet Series™	TinyPWM™
CTL™	IntelliMAX™	RapidConfigure™	TinyWire™
Current Transfer Logic™	ISOPLANAR™	 ™	TranSiC™
DEUXPEED®	Making Small Speakers Sound Louder and Better™	Saving our world, 1mW/W/kW at a time™	TriFault Detect™
Dual Cool™	MegaBuck™	SignalWise™	TRUECURRENT®*
EcoSPARK®	MICROCOUPLER™	SmartMax™	µSerDes™
EfficientMax™	MicroFET™	SMART START™	 SerDes™
ESBC™	MicroPak™	Solutions for Your Success™	UHC®
 Fairchild®	MicroPak2™	SPM®	Ultra FRFET™
Fairchild Semiconductor®	MillerDrive™	STEALTH™	UniFET™
FACT Quiet Series™	MotionMax™	SuperFET®	VCX™
FACT®	MotionGrid®	SuperSOT™-3	VisualMax™
FAST®	MTi®	SuperSOT™-6	VoltagePlus™
FastvCore™	MTx®	SuperSOT™-8	XS™
FETBench™	MVN®	SupreMOS®	Xsens™
FPS™	mWSaver®	SyncFET™	仙童™
	OptoHiT™	Sync-Lock™	
	OPTOLOGIC®		

* Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. TO OBTAIN THE LATEST, MOST UP-TO-DATE DATASHEET AND PRODUCT INFORMATION, VISIT OUR WEBSITE AT [HTTP://WWW.FAIRCHILDSEMI.COM](http://www.fairchildsemi.com). FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
2. A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address any warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

Rev. I72